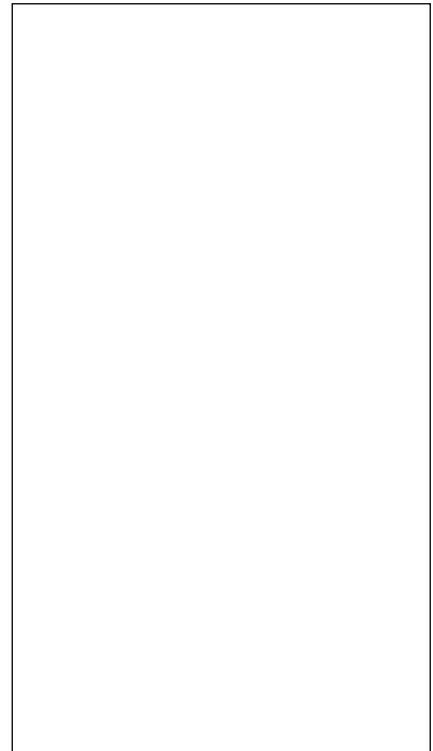


## DESCRIPTION:

The T1620H-8E triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Compared to traditional triacs, T1620H-8E provides a very high switching capability up to junction temperatures of 150°C. Package TO-263 is RoHS compliant.



## MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	16	A
$V_{DRM}/V_{RRM}$	800	V
$I_{GT} / /$	20/20/20	mA

## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-150	
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	800	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	800	V
RMS on-state current ( $T_c 0125^\circ\text{C}$ )	$I_{T(RMS)}$	16	A
Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I_{TSM}$	160	A
Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$ , $T_j=25^\circ\text{C}$ )		176	
$I^2t$ value for fusing ( $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I^2t$	128	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}$ , $f=100\text{Hz}$ , $T_j=150^\circ\text{C}$ )	$di/dt$	100	$\text{A/s}$
Peak gate current ( $t_p=20\text{ }\mu\text{s}$ , $T_j=150^\circ\text{C}$ )	$I_{GM}$	4	A
Average gate power dissipation ( $T_j=150^\circ\text{C}$ )	$P_{G(AV)}$	1	W
Peak gate power	$P_{GM}$	10	W

Peak pulse voltage ( $T_j=25$ ; non-repetitive, off-state; FIG.8)	$V_{pp}$	4	kV
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### ELECTRICAL CHARACTERISTICS (unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
$I_{GT}$	$V_D=12V$ $R_L=33$	- -	MAX.	20	mA
$V_{GT}$		- -	MAX.	1	V
$V_{GD}$	$V_D=V_{DRM}$ $T_j=150$ $R_L=3.3K$	- -	MIN.	0.2	V
$I_L$	$I_G=1.2I_{GT}$	-	MAX.	40	mA
				55	
$I_H$	$I_T=500mA$		MAX.	30	mA
$dV/dt$	$V_D=540V$ Gate Open $T_j=150$		MIN.	1000	V/s
$(dI/dt)_c$	$V_{GS}=150V$ $T_j=150$		MIN.	12	A/ms
$t_{on}$	$I_G=40mA$ $I_A=200mA$ $I_R=20mA$ $T_j=25$		TYP.	8	s
$t_{off}$				60	

### STATIC CHARACTERISTICS

Symbol



FIG.1 Maximum power dissipation versus RMS on-state current

FIG.2: RMS on-state current versus case temperature

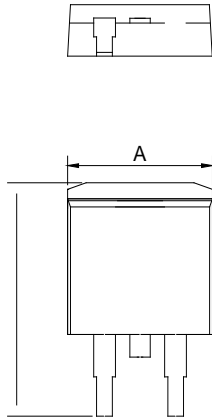
GT  
FIG.7 Relative variations of gate trigger current,

FIG.8 ÖTest circuit for inductive and resistive loads to IEC-61000-4-5 standards



T1620H-8E

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.40		9.60	0.37		0.378
D	2.40			0.094		
E	1.20		1.50	0.047		0.059
F	0.75		0.85	0.029		0.033
G			1.50			
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0		0.25			
M	1.25		1.35			

DELIVERY MODE



